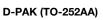
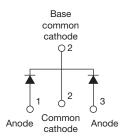


Vishay Semiconductors

Hyperfast Rectifier, 2 x 4 A FRED Pt®



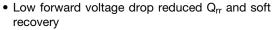




PRODUCT SUMMARY					
Package	D-PAK (TO-252AA)				
I _{F(AV)}	2 x 4 A				
V_{R}	200 V				
V _F at I _F	0.95 V				
t _{rr} (typ.)	23 ns				
T _J max.	175 °C				
Diode variation	Common cathode				

FEATURES

- Hyperfast recovery time
- 175 °C max. operating junction temperature
- · Output rectification freewheeling





HALOGEN

FREE

- Low leakage current
- Compliant to RoHS Directive 2002/95/EC
- Halogen-free according to IEC 61249-2-21 definition
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C

DESCRIPTION/APPLICATIONS

State of the art hyperfast recovery rectifiers designed with optimized performance of forward voltage drop, hyperfast recovery time, and soft recovery.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in PFC boost stage in the AC/DC section of SMPS inverters or as freewheeling diodes. Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Peak repetitive reverse voltage	V_{RRM}		200	V			
Average rectified forward current	I _{F(AV)}	T _C = 164 °C	8	۸			
Non-repetitive peak surge current per leg	I _{FSM}	T _J = 25 °C	80	A			
Operating junction and storage temperatures	T _J , T _{Stg}		- 65 to 175	°C			

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Breakdown voltage, blocking voltage	V _{BR} , V _R	Ι _R = 100 μΑ	200	-	-			
		I _F = 4 A	-	0.87	0.95	V		
Forward voltage per leg	V _F	I _F = 8 A	-	0.95	1.10			
		I _F = 4 A, T _J = 150 °C	-	0.71	0.80			
		I _F = 8 A, T _J = 150 °C	-	0.8	1.0			
		$V_R = V_R$ rated	-	-	4			
Reverse leakage current per leg	I _R	T _J = 125 °C, V _R = V _R rated	-	-	40	μA		
		T _J = 150 °C, V _R = V _R rated	-	-	80			
Junction capacitance per leg	C _T	V _R = 200 V	-	17	=	pF		
Series inductance	L _S	Measured lead to lead 5 mm from package body	-	8	-	nH		

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VS-8CWH02FN-M3

Vishay Semiconductors Hyperfast Rectifier, 2 x 4 A FRED Pt®



DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CO	MIN.	TYP.	MAX.	UNITS		
		$I_F = 1 A, dI_F/dt = 10$	00 A/μs, V _R = 30 V	-	23	27		
Reverse recovery time	t _{rr}	T _J = 25 °C	$I_F = 4 \text{ A}$ $dI_F/dt = 200 \text{ A/}\mu\text{s}$ $V_R = 160 \text{ V}$	-	20	-	ns	
		T _J = 125 °C		-	27	-		
Peak recovery current	I _{RRM}	T _J = 25 °C		-	2	-	^	
		T _J = 125 °C		-	3.4	-	A	
Reverse recovery charge	Q _{rr}	T _J = 25 °C		-	20	-	nC	
		T _J = 125 °C		-	46	-		

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Maximum junction and storage temperature range	T _J , T _{Stg}		- 65	-	175	°C		
Thermal resistance, per leg	D		-	2.7	3.2	°C/W		
junction to case per device	R_{thJC}		-	1.35	1.6	C/VV		
Approximate weight				0.3		g		
Approximate weight				0.01		OZ.		
Marking device		Case style D-PAK (TO-252AA)		8CWF	102FN	•		



Hyperfast Rectifier, 2 x 4 A FRED Pt® Vishay Semiconductors

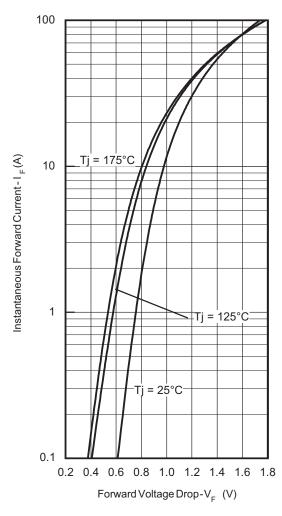


Fig. 1 - Typical Forward Voltage Drop Characteristics

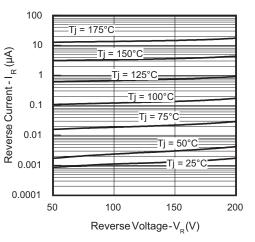


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

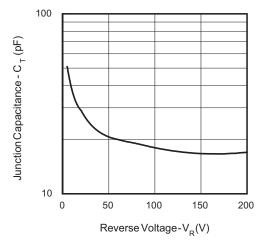


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

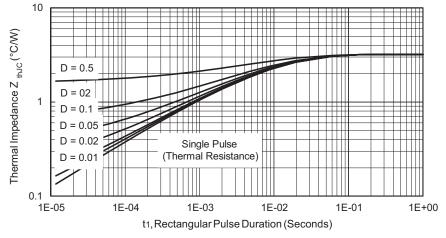


Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics

Vishay Semiconductors Hyperfast Rectifier, 2 x 4 A FRED Pt®



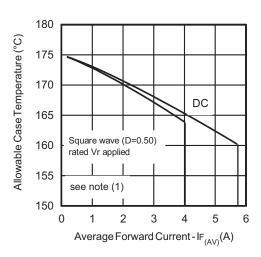


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

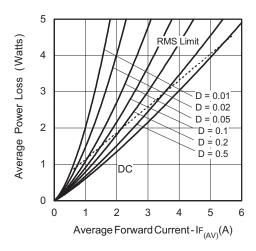


Fig. 6 - Forward Power Loss Characteristics

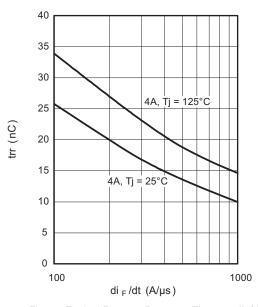


Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt

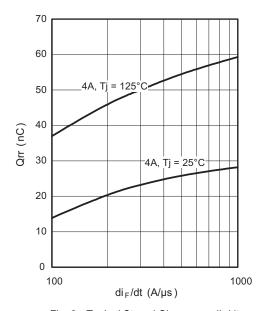


Fig. 8 - Typical Stored Charge vs. dl_F/dt

Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$; Pd = Forward power loss = $I_{F(AV)} \times V_{FM}$ at $(I_{F(AV)}/D)$ (see fig. 6); Pd_{REV} = Inverse power loss = $V_{R1} \times I_R (1 - D)$; I_R at V_{R1} = Rated V_R



Hyperfast Rectifier, 2 x 4 A FRED Pt® Vishay Semiconductors

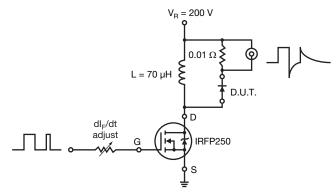
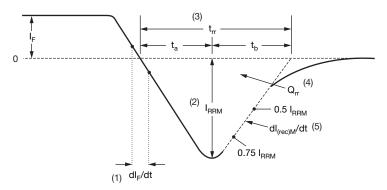


Fig. 9 - Reverse Recovery Parameter Test Circuit



- (1) dI_F/dt rate of change of current through zero crossing
- (2) I_{RRM} peak reverse recovery current
- (3) $t_{\rm rr}$ reverse recovery time measured from zero crossing point of negative going I_F to point where a line passing through 0.75 I_{RRM} and 0.50 I_{RRM} extrapolated to zero current.
- (4) Q_{rr} area under curve defined by t_{rr} and I_{RRM}

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

(5) $dl_{(rec)M}/dt$ - peak rate of change of current during t_b portion of t_{rr}

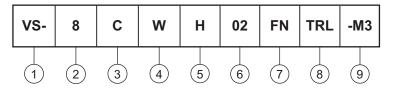
Fig. 10 - Reverse Recovery Waveform and Definitions

Vishay Semiconductors Hyperfast Rectifier, 2 x 4 A FRED Pt®



ORDERING INFORMATION TABLE

Device code



- Vishay Semiconductors product
- Current rating (8 = 8 A)
- Circuit configuration:

C = Common cathode

Package identifier:

W = D-PAK

- H = Hyperfast recovery
- Voltage rating (02 = 200 V)
- FN = TO-252AA
- None = Tube
 - TR = Tape and reel
 - TRL = Tape and reel (left oriented)
 - TRR = Tape and reel (right oriented)
- 9 Environmental digit:

-M3 = Halogen-free, RoHS compliant and terminations lead (Pb)-free

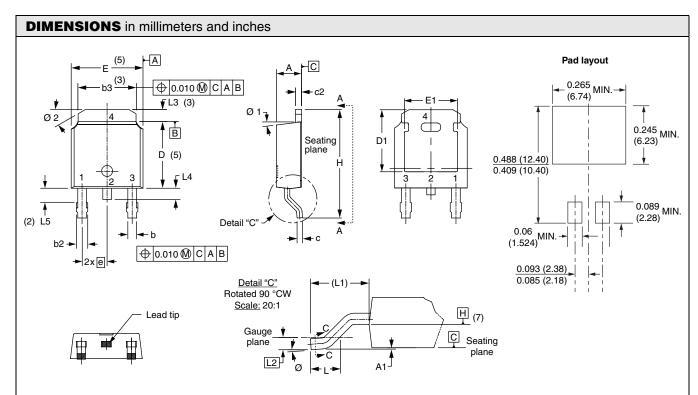
ORDERING INFORMATION (Example)							
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION				
VS-8CWH02FN-M3	75	3000	Antistatic plastic tube				
VS-8CWH02FNTR-M3	2000	2000	13" diameter reel				
VS-8CWH02FNTRL-M3	3000	3000	13" diameter reel				
VS-8CWH02FNTRR-M3	3000	3000	13" diameter reel				

LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?95016				
Part marking information	www.vishay.com/doc?95176				
Packaging information	www.vishay.com/doc?95033				
SPICE model	www.vishay.com/doc?95375				



Vishay High Power Products

D-PAK (TO-252AA)



SYMBOL	MILLIM	ETERS	INC	NOTES	
STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	2.18	2.39	0.086	0.094	
A1	-	0.13	-	0.005	
b	0.64	0.89	0.025	0.035	
b2	0.76	1.14	0.030	0.045	
b3	4.95	5.46	0.195	0.215	3
С	0.46	0.61	0.018	0.024	
c2	0.46	0.89	0.018	0.035	
D	5.97	6.22	0.235	0.245	5
D1	5.21	-	0.205	1	3
Е	6.35	6.73	0.250	0.265	5
E1	4.32	-	0.170	-	3

SYMBOL	MILLIMETERS		INC	NOTES	
STWBOL	MIN.	MAX.	MIN.	MAX.	NOTES
е	2.29	BSC	0.090	0.090 BSC	
Н	9.40	10.41	0.370	0.410	
L	1.40	1.78	0.055	0.070	
L1	2.74 BSC		0.108 REF.		
L2	0.51	0.51 BSC		0.020 BSC	
L3	0.89	1.27	0.035	0.050	3
L4	-	1.02	-	0.040	
L5	1.14	1.52	0.045	0.060	2
Ø	0°	10°	0°	10°	
Ø1	0°	15°	0°	15°	
Ø2	25°	35°	25°	35°	

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension uncontrolled in L5
- (3) Dimension D1, E1, L3 and b3 establish a minimum mounting surface for thermal pad
- (4) Section C C dimension apply to the flat section of the lead between 0.13 and 0.25 mm (0.005 and 0.10") from the lead tip
- (5) Dimension D, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (6) Dimension b1 and c1 applied to base metal only
- $^{(7)}$ Datum A and B to be determined at datum plane H
- (8) Outline conforms to JEDEC outline TO-252AA



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